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TITLE OF THE INVENTION

SPUTTERING POWER-SUPPLY UNIT

CROSS-REFERENCE TO RELATED APPLICATIONS

This is a Continuation Application of PCT
5 Application No. PCT/JP02/09827, filed September 25,
2002, which was not published under PCT Article 21(2)
in English.

This application is based upon and claims the
benefit of priority from the prior Japanese Patent
10 Applications No. 2001-303689, filed September 28, 2001;
and No. 2001-303691, filed September 28, 2001, the
entire contents of both of which are incorporated
herein by reference.

BACKGROUND OF THE INVENTION

15 1. Field of the Invention

The present invention relates to a sputtering
power-supply unit for use in a sputtering device for
the manufacture of a compact disc (CD) or a digital
versatile disk (DVD).

20 2. Description of the Related Art

A sputtering power-supply unit for use in a
sputtering device for the manufacture of a compact disc
(CD) or a digital versatile disk (DVD) is known in
Japanese Patent No. 2835322, Japanese Patent
25 No. 2835323 and USP 5,576,939.

Formation of a film on the compact disc or the
digital versatile disk is carried out by a magnetron

sputtering technology. If suppression of arc discharge fails during this sputtering, a target material is scattered to adhere to the disk, with the result that production yield is reduced. Accordingly, if arc
5 discharge occurs during the sputtering, a reverse voltage is generated to suppress the occurrence of the arc discharge. However, an arc suppression circuit has been destroyed sometimes because of disconnection of an output cable or the like.

10 Furthermore, in order to complete the film formation on the disk within a short time, it is necessary to increase the average power output from the sputtering power-supply unit.

15 However, when the average power is increased, arc discharge easily occurs during the sputtering, increasing the number of times when the suppression of the arc discharge fails.

20 It is desired that even if such arc discharge occurs, fluctuation in the sputtering current is reduced to stably continue sputtering discharge.

BRIEF SUMMARY OF THE INVENTION

25 An object of the present invention is to provide a sputtering power-supply unit which can reduce fluctuation in a sputtering current even if arc discharge occurs.

Another object of the present invention is to provide a sputtering power-supply unit less prone to

breakdown.

A sputtering power-supply unit according to a first embodiment of the present invention comprises: a voltage generation section which generates
5 a sputtering voltage between a negative electrode output terminal and a positive electrode output terminal; and a circuit section which reduces fluctuation in a sputtering current even if arc discharge occurs between the negative electrode output
10 terminal and the positive electrode output terminal.

That is, according to the sputtering power-supply unit of the first embodiment of the present invention, by disposing the circuit section which reduces fluctuation in a sputtering current even if arc
15 discharge occurs between the negative electrode output terminal and the positive electrode output terminal, it is possible to reduce fluctuation in a sputtering current even if arc discharge occurs.

A sputtering power-supply unit according to
20 another embodiment of the present invention, which has a negative electrode output terminal and a positive electrode output terminal, comprises: a DC power source which generates an output of a predetermined voltage; a switching circuit which has a plurality of switching
25 elements connected to bridges, and converts an output of the DC power source into a pulse output; a transformer which receives a primary pulsed voltage

from the switching circuit, and outputs a secondary pulsed voltage; a rectification circuit which rectifies the secondary pulsed voltage output from the transformer; a choke coil connected to an output side
5 of the rectification circuit; a reverse voltage generation source; a switching section disposed between the reverse voltage generation source and the choke coil; a constant voltage element connected in parallel with the switching section; and a control section which
10 outputs a switching control signal to the switching element, and a switching control signal to control opening/closing of the switching section.

That is, according to the sputtering power-supply unit of the other embodiment of the present invention,
15 it is possible to prevent destruction of the switching section operated when a reverse voltage is generated.

BRIEF DESCRIPTION OF THE SEVERAL VIEWS OF THE DRAWING

FIG. 1 is a constitutional view of a sputtering power-supply unit according to a first embodiment of
20 the present invention.

FIG. 2 is a constitutional view of a sputtering power-supply unit according to a second embodiment of the present invention.

FIG. 3 is a constitutional view of a sputtering power-supply unit according to a third embodiment of
25 the present invention.

FIG. 4 is a constitutional view of a sputtering

power-supply unit according to a fourth embodiment of the present invention.

FIG. 5 is a waveform chart explaining an operation of the fourth embodiment.

5 FIG. 6 is a constitutional view of a sputtering power-supply unit according to a fifth embodiment of the present invention.

10 FIG. 7 is a constitutional view of a sputtering power-supply unit according to a sixth embodiment of the present invention.

FIG. 8 is a constitutional view of a sputtering power-supply unit according to a seventh embodiment of the present invention.

15 FIG. 9 is a constitutional view of a sputtering power-supply unit according to an eighth embodiment of the present invention.

FIG. 10 is a constitutional view of a sputtering power-supply unit according to a ninth embodiment of the present invention.

20 FIG. 11 is a constitutional view of a sputtering power-supply unit according to a tenth embodiment of the present invention.

25 FIG. 12 is a constitutional view of a sputtering power-supply unit according to an eleventh embodiment of the present invention.

FIG. 13 is a constitutional view of a sputtering power-supply unit according to a twelfth embodiment of

the present invention.

FIG. 14 is a constitutional view of a sputtering power-supply unit according to a thirteenth embodiment of the present invention.

5 FIG. 15 is a constitutional view of a sputtering power-supply unit according to a fourteenth embodiment of the present invention.

DETAILED DESCRIPTION OF THE INVENTION

Hereinafter, an embodiment of the present
10 invention will be described with reference to the accompanying drawings. In FIG. 1, reference numeral 10 denotes a control section which controls a sputtering power-supply unit.

Reference numeral 11 denotes a sputtering DC power
15 source of, e.g., 800 V. Between both electrodes of this DC power source 11, a capacitor 12 is connected in parallel.

The negative electrode of the DC power source 11
is connected to the source of a switching transistor
20 SW1.

A flywheel diode 13 is connected between the drain
of the switching transistor SW1 and the positive
electrode of the DC power source 11. The drain of the
switching transistor SW1 is connected through a choke
25 coil L to the source of a switching transistor SW2.
The positive electrode of a reverse voltage source 14
is connected to the drain of this switching transistor

SW2. The negative electrode of the reverse voltage source 14 is connected to a ground line a.

The source of the transistor SW2 is connected to the cathode of a diode 15. A resistor R1 is connected
5 in parallel with the diode 15. The diode 15 and the resistor R1 constitute a reverse direction arc prevention circuit.

The anode of the diode 15 is connected to the negative electrode (-) of the sputtering power-supply
10 unit. The ground line a is connected to the positive electrode (+) thereof.

A load voltage VM between the negative electrode (-) and the positive electrode (+) of the sputtering power-supply unit is detected by a voltage detection
15 section 16. Here, the sputtering voltage is normally 300 V or higher and the arc discharge voltage is 150 V or lower during sputtering discharge in a chamber 19. Thus, detection of the load voltage VM enables determination as to normal execution of sputtering and
20 occurrence of arc discharge.

Further, a current detector 17 is disposed between the anode of the diode 13 and the choke coil L. A load current CM is detected by this current detector 17.

The negative electrode (-) is connected to
25 a target 18, and the positive electrode (+) is connected to the chamber 19.

Incidentally, the load voltage detected by the

voltage detection section 16 and the load current detected by the current detector 17 are input to a controller 10. The controller 19 detects the load voltage VM, determines the occurrence of arc discharge
5 in the chamber 19 if the voltage is 150 V or lower, turns ON a gate signal SW2 to output it to the transistor SW2, and accordingly makes the transistor SW2 conduct.

The load voltage VM detected by the voltage
10 detection section 16 and the load current CM detected by the current detector 17 are multiplied by an analog multiplier 21 to calculate instantaneous power P. Then, the difference between this instantaneous power P and set power Pset, i.e., error power, is calculated,
15 and input through a switch S1 to a power feedback error amplifier 22. At this error amplifier 22, the error power is integrated. Here, the switch S1 is circuit-opened (opened) when a gate control signal SW2 output from the controller 10 is turned ON to be output.

20 Then, the output of the error amplifier 22 is input as a set current value Iset to an error amplifier 23. The error amplifier 23 amplifies the difference between the load current CM and the set current value Iset to output it to a PWMIC 24. This
25 PWMIC 24 outputs a signal having a pulse width in accordance with the difference between the load current CM and the set current value Iset to a driver 25.

A gate control signal SW1 is output from the driver 25 to the transistor SW1.

Next, operation will be described. If sputtering is carried out in the chamber 19 in a state of no arc generation, a sputtering voltage of 300 V or higher is detected as a load voltage by the voltage detection section 16.

Accordingly, the controller 10 turns OFF the gate control signal SW2. That is, a reverse voltage supply 14 is not applied to suppress arc generation.

In such a state, the switch S1 is closed. Thus, the load voltage VM detected by the voltage detection section 16 and the load current CM detected by the current detector 17 are multiplied by the analog multiplier 21 to calculate instantaneous power P. Then, the difference between this instantaneous power P and set power Pset, i.e., error power, is calculated, and input through the switch S1 to a power feedback error amplifier 22. At this error amplifier 22, the error power is integrated.

Then, the output of the error amplifier 22 is input as a set current value Iset to an error amplifier 23. The error amplifier 23 amplifies the difference between the load current CM and the set current value Iset to output it to the PWMIC 24. This PWMIC 24 outputs a signal having a pulse width in accordance with the difference between the load current

CM and the set current value I_{set} to the driver 25.
The transistor SW1 is ON/OFF controlled by the
driver 25.

That is, feedback control is carried out to
5 realize the set power P_{set} , and the set current value
 I_{set} is set based on the difference between the
instantaneous power of the sputtering power-supply unit
and the set power P_{set} .

On the other hand, when an arc is generated in the
10 chamber 9, the load voltage VM detected by the voltage
detection section 16 is reduced to 150 V or lower.
Then, the gate control signal SW2 output from the
controller 10 is turned ON to output a positive voltage
output from the reverse voltage source 14 to the
15 chamber 19, whereby the arc generation is suppressed.

Since the gate control signal SW2 is turned ON,
the switch S1 is turned OFF. Thus, the set current
value I_{set} output from the error amplifier 22 is
maintained at a value immediately before arc generation
20 in the chamber 19.

Normally, when the sputtering power-supply unit is
constant-power run by the set power P_{set} , if an arc is
generated in the chamber 19, reducing the load voltage
VM, control is carried out to increase the load current
25 CM. According to the first embodiment, however, if an
arc is generated, since the switch S1 is opened to
maintain the set current value I_{set} at the value before

the arc generation, i.e., before the sputtering, it is possible to prevent an abrupt increase in the load current CM even if an arc is generated.

Next, a second embodiment of the present invention will be described by referring to FIG. 2. In FIG. 2, portions similar to those of FIG. 1 are denoted by similar reference numerals, and detailed description thereof will be omitted.

The load current CM detected by the current detector 17 is input to a (-) terminal of a comparator 31. The set current value Iset is input to a (+) terminal of the comparator 31. An output of the comparator 31 is feedback through a resistor 32 to the (+) terminal of the comparator 31.

The driver 25 is connected to the output of the comparator 31. The gate control signal SW1 is output from the driver 25 to the transistor SW1.

Next, an operation of the second embodiment will be described. Since the output of the comparator 31 is feedback through the resistor 32 to the + terminal, it functions as a comparator which has hysteresis.

At a (+) input terminal of the comparator 31, a circuit constant of the resistor 32 or the like is decided to be a value higher by, e.g., 5% than that of the set current value Iset.

First, as the load current CM is zero, an input voltage of the (-) terminal of the comparator 31 is

zero V. Accordingly, the output of the comparator 31 becomes +, and the gate control signal SW1 is turned ON by the driver 25 to be output to the transistor SW1. Thus, the transistor SW1 conducts, and the DC power source 11 is supplied to the chamber 19, whereby sputtering discharge is carried out.

Incidentally, when the transistor SW1 conducts, the load current CM is increased in accordance with the equation:

$$(\text{voltage of DC power source 11} - \text{load voltage}) = L \cdot di/dt$$

Then, when the load current CM becomes larger than $I_{set} \cdot 1.05$, the output of the comparator 31 becomes zero V to turn OFF the gate control signal SW1 and to turn OFF the transistor SW1.

When the transistor SW1 is turned OFF, the load current CM is reduced in accordance with the equation:

$$(-\text{load voltage } V_M) = L \cdot di/dt$$

When the load current CM becomes lower than the set current value $I_{set} \cdot 0.95$, the output of the comparator 31 becomes + to turn ON the transistor SW1. As a result of repeating such an operation, it is possible to limit the load current CM to $\pm 5\%$ of the set current value I_{set} .

Next, a third embodiment of the present invention will be described by referring to FIG. 3. In FIG. 3, portions similar to those of FIG. 1 and FIG. 2 are

denoted by similar reference numerals, and detailed description thereof will be omitted. According to the third embodiment, as shown in FIG. 2, the transistor SW1 is driven and controlled based on the output of the
5 comparator which has hysteresis.

As described above with reference to FIG. 1, the set current value I_{set} input to the (+) terminal of the comparator 31 is set based on an error between the instantaneous power and the set power P_{set} of the
10 sputtering power-supply unit.

Then, by the comparator 31 which has hysteresis, the load current I_L can be limited to $\pm 5\%$ of the set current value I_{set} .

Further, according to the third embodiment, the
15 set current I_{set} is decided so that power supplied to the chamber 19 can be equal to the set power P_{set} . Moreover, when arc is generated in the chamber 19, by turning OFF the switch S1, the error amplifier 22 maintains a value immediately before the arc generation
20 in the chamber 19. Accordingly, while the power supplied into the chamber 19 is controlled to be equal to the set power P_{set} , it is possible prevent an increase of the load current I_L caused by arc generation in the chamber 19.

25 Next, a fourth embodiment of the present invention will be described by referring to FIG. 4. In FIG. 4, a 3-phase AC voltage (AC 200 V $\sqrt{3}$) is subjected to

all-wave rectification at a 3-phase rectification circuit D0, passed through a filter L0, pulse-output by a pair of switching circuits S10, S20, and then connected to a primary side of a transformer T1.

5 The switching circuit S10 has switching elements S11 to S14. The switching elements S11 and S13 are serially connected, and the switching elements S12 and S14 are serially connected. Further, the two serially connected bodies are connected in parallel. ON/OFF
10 control of these switching elements S11 to S14 is carried out based on a gate control signal from a later-described driver.

 Additionally, a smoothing capacitor C11 is connected in parallel to the switching circuit S10.

15 A secondary side of the transformer T1 is connected to bridge circuits B1, B2 constituted of four diodes.

 One end of the bridge circuit B1 connected through four serially connected independent choke coils L1 to
20 L4, and further through a reverse-direction arc prevention circuit 41 to a (-) output terminal O1 of the unit. In this reverse-direction arc prevention circuit 41, a resistor R0 is connected in parallel to a diode D2.

25 Further, the other end of the bridge circuit B1 is connected to a (+) output terminal O2 of the unit. Additionally, a connection point between the choke coil

L4 and the reverse-direction arc prevention circuit 41 is connected through a switching transistor (referred to as a switch SW2, hereinafter) to an anode of a reverse voltage holding capacitor C31.

5 The other end of the bridge circuit B1 is connected to one end of the bridge circuit B2. A connection point between the bridge circuits B1 and B2 is connected to a cathode of the capacitor C31, and to the (+) output terminal O2 of the unit.

10 A current flowing through the four serially connected independent choke coils L1 to L4 is detected by a current detector 22.

 The (-) output terminal O1 of the unit is connected to the target 18, and the (+) output terminal
15 O2 is connected to the chamber 19. Normally, the (+) output terminal O2 of the unit is grounded.

 The controller 10 detects the load voltage VM detected by the voltage detection section 16 of the (-) output terminal O1 and the (+) output terminal O2 of
20 the unit to determine occurrence of sputtering discharge or arc discharge in the chamber 19. Since a sputtering voltage is normally 300 V or higher, and an arc discharge voltage is 150 V or lower, when a potential difference V between the (-) output
25 terminal O1 and the (+) output terminal O2 of the unit is reduced to 150 V or lower, the occurrence of arc discharge in the chamber 19 is determined.

Upon detection of the occurrence of arc discharge, the controller 10 turns ON the switch SW2 for set time T2 (0.3 to 10 μ s) after passage of set time T1 (0.01 to 100 μ s). That is, a reverse voltage pulse is applied to the target 18. During this period, the switching elements S11 to S14 are controlled to be ON/OFF by a later-described driver so that a constant current can flow through the four serially connected independent choke coils L1 to L4. That is, the load current CM flowing through the four serially connected independent choke coils L1 to L4 is detected by the current detector 22. Arc determination time T3 immediately after the application of the aforementioned reverse voltage pulse is set to 10 μ s (0.01 to 10 μ s) or lower. Then, if arc is determined again after passage of the arc determination time T3, a process is carried out to turn ON the switch SW2 for set time T2 (0.3 to 10 μ s) after the set time T1 (0.01 to 100 μ s). Thereafter, while arc is detected, the reverse voltage pulse is continuously applied until no arc is detected. Here, the switch SW2 is turned ON after the set time T1 from the arc determination because the arc may be self-quenched before the passage of the set time T1.

A current CT flowing through the primary coil of the transformer T1 is detected by a current detector 42. A reason for detecting the current flowing through the primary coil of the transformer T1

is that unless primary currents are alternately supplied within set time, magnetic saturation occurs in the transformer T1 to supply a large current, consequently destroying the switching elements S11 to S14.

5 The current CT flowing through the primary coil of the transformer T1, which is detected by the current detector 22, is input to a - terminal of a comparator 51, and a limiting current CT lim of the transformer T1
10 is input to a + terminal thereof.

Further, the load current CM detected by the current detector 22 is input to the - terminal of the comparator 31 which has hysteresis described above with reference to FIG. 2. The set current value Iset is
15 input to the + terminal of the comparator 31.

Further, the output of the comparator 31 is output to a CR oscillation circuit 52. The output of the comparator 31 is input through a resistor 52a to a + terminal of a comparator 52b, and through
20 a resistor 52c, a capacitor 52d to a - terminal of the comparator 52b. Thus, while the output of the comparator 31 is positive, the capacitor 52d is charged to increase an input potential of the - terminal thereof. At a point of time when the input potential
25 of the - terminal of the comparator 52d becomes higher than that of the + terminal, an output of the comparator 52d becomes zero. The capacitor 52d is

suddenly discharged, and becomes a + output at a point of time when it is lower than hysteresis setting of a + input.

Thus, while the output of the comparator 31 is positive, the CR oscillation circuit 52 continues oscillation.

The outputs of the comparators 51, 31 and the CR oscillation circuit 52 are input to an AND circuit 53. An output of the AND circuit 53 is input to a T input terminal of a T type FF 54, and to one input terminal of AND circuits 55a, 55b. A Q output of the T type FF 54 is input to the other input terminal of the AND circuit 55a, and its \bar{Q} output is input to the other input terminal of the AND circuit 55b.

An output of the AND circuit 55a is output to a driver 56a, and an output of the AND circuit 55b is output to a driver 56b. Conduction of the switching elements S11, S14 is controlled by the driver 56a, and conduction of the switching elements S13, S12 is controlled by the driver 56b.

By the foregoing constitution, while the output of the comparator 31 is positive, the CR oscillation circuit 52 continues oscillation. Thus, for the Q output of the T type FF 54, "1" and "0" are alternately output. As a result, the drivers 56a, 56b are alternatively driven. By disposing the CR oscillation circuit as described above, it is possible to control

the current flowing through the primary coil of the transformer T1 without magnetically saturating the transformer T1.

5 In the case of controlling the current flowing through the primary coil of the transformer T1, if a first pulse width is set largest, magnetic saturation occurs by a probability of 1/2. Thus, in the normal drivers 56a, 56b, magnetic saturation is prevented by setting a time constant of the error amplifier to be 5
10 to 10 times larger than a pulse cycle to gradually increase a pulse width as shown in FIG. 5.

In the case of using the comparator 31 which has hysteresis, since a first pulse is fully open, magnetic saturation occurs by a probability of 1/2. Thus, when
15 an initial current is detected by the current detector 42, and its value is determined to be larger than CT lim by the comparator 51, the output of the comparator 51 becomes zero. Accordingly, magnetic saturation of the transformer T1 is prevented by
20 stopping pulses output from the drivers 56a, 56b.

Next, a fifth embodiment of the present invention will be described by referring to FIG. 6. In FIG. 6, portions similar to those of FIG. 1 and FIG. 4 are denoted by similar reference numerals, and detailed
25 description thereof will be omitted. According to the fifth embodiment, the set current value Iset input to the + terminal of the comparator 31 which has

hysteresis shown in FIG. 4 is set based on the error between the momentary power and the set power Pset of the sputtering power-supply unit as described above with reference to FIG. 1.

5 By the comparator 31 which has hysteresis, the load current CM can be set to $\pm 5\%$ of the set current value Iset.

 According to the fifth embodiment, the set current Iset is decided so that power supplied to the chamber
10 19 can be equal to the set power Pset. Further, if arc is generated in the chamber 19, the switch S1 is turned OFF to maintain a value immediately before arc generation in chamber 19 by the error amplifier 22.

 Thus, according to the fifth embodiment, in
15 addition to the effects of the fourth embodiment, it is possible to prevent an increase of the load current CM if arc is generated in the chamber 19 while the power supplied into the chamber 19 is controlled to be equal to the set power Pset.

20 Next, a sixth embodiment of the present invention will be described by referring to FIG. 7. First, a basic principle of the sixth embodiment will be described. A relation between a current and a voltage flowing through the coil L is represented by the
25 following equation:

$$E = L \cdot di/dt \quad \dots (1)$$

 In the equation (1), if L is inductance, Vi

a supply pulse, V_o an output voltage, T a PWM cycle, dt a pulse width, I_s a target current, and I_r a present current, then the current di changed per cycle of the PWM is represented by the following equation:

5 $di = (V_i - V_o)/L \cdot dt - V_o/L \cdot (T - dt) \quad \dots (2)$

In the equation (2), a first term means that a PWM pulse is turned ON to increase a current, and a second term means that the PWM pulse is turned OFF to supply energy stored in L to a load, thereby reducing
10 a current.

Next, the equation (2) is developed:

$$\begin{aligned} di &= V_i/L \cdot dt - V_o/L \cdot dt - V_o/L \cdot T + V_o/L \cdot dt \\ &= V_i/L \cdot dt - V_o/L \cdot T \quad \dots (3) \end{aligned}$$

In the equation (3), a first term means that a PWM pulse is turned ON to increase a current, and a second
15 term means that V_o is output during a cycle T . Thus, a current is considered to be reduced there between.

Since the amount of control is a PWM pulse width dt , if equation (3) is solved for dt , it becomes as
20 follows:

$$\begin{aligned} di + V_o/L \cdot T &= V_i/L \cdot dt \\ dt &= (di + V_o/L \cdot T) \cdot L/V_i \\ &= di \cdot L/V_i + V_o/V_i \cdot T \quad \dots (4) \end{aligned}$$

In the equation (4), a first term means a
25 correction pulse width for a current excess or shortage, and a second term means a pulse width necessary for maintaining a present current by a ratio

of an input voltage and an output voltage.

Further, because of $d_i = I_s - I_r$,
the equation (4) is changed to:

$$= (I_s - I_r) * L / V_i + V_o / V_i * T$$

5
$$= I_s * L / V_i - I_r * L / V_i + V_o / V_i * T \quad \dots (5)$$

$$= (I_s * L - I_r * L + V_o * T) / V_i \quad \dots (6)$$

Here, in the equation (5), a first term means
a pulse width for a set current, a second term means
a pulse width for a present current, and a third term
10 means a pulse width necessary for maintaining the
current.

A circuit on a lower side of FIG. 7 is a circuit
view of the equation (6). That is, I_s , I_r , V_o of
the equation (6) are equivalent to a set current value
15 I_{set} , a load current C_M , and a load voltage V_M of
FIG. 7.

The load voltage V_M , the load current C_M , the set
current value I_{set} are input to a - terminal of the
operational amplifier 61. At this operational
20 amplifier 61, $I_{set} * L - C_M * L + V_M * T$ is calculated.

Then, at a divider 62, a process of dividing
an output of the operational amplifier 61 by an input
voltage V_i is carried out. Then, an output of the
divider 62 is output to the PWMIC 24. A pulse width is
25 decided by this PWMIC 24. Further, the driver 25 is
connected to an output of the PWMIC 24, and a gate
control signal $SW1$ is output to the transistor $SW1$ by

this driver 25.

As described above, by carrying out an arithmetic operation based on the equation (6) at the operational amplifier 61 and the divider 62, a pulse width is
5 decided by the PWMIC 24.

Thus, according to the sixth embodiment, since the pulse width is calculated by an average current of the cycle T as shown in the equation (6), in order to sufficiently reduce current ripples, inductance L is
10 enlarged to enable shortening of the cycle T. That is, a PWM switching speed can be increased. Moreover, if the load voltage VM is reduced due to arc generation in the chamber 19, since a calculation result of the pulse width is obtained at a point of time when the load
15 voltage VM is reduced, it is possible to limit an increase of the load current CM smaller.

Next, a seventh embodiment of the present invention will be described by referring to FIG. 8. In FIG. 8, portions similar to those of FIG. 7 or
20 FIG. 1 are denoted by similar reference numerals, and detailed description will be omitted.

In FIG. 8, a set current value Iset input to a - terminal of the operational amplifier 61 is set based on an error between the instantaneous power and
25 the set power Pset of the sputtering power-supply unit.

That is, the seventh embodiment provides the following effects in addition to those of the

aforementioned sixth embodiment. That is, the set current I_{set} is decided so that power supplied to the chamber 19 can be equal to the set power P_{set} . Further, if arc is generated in the chamber 19, the
5 switch S_1 is turned OFF to hold a value immediately before the arc generation in the chamber 19 by the error amplifier 22. Thus, during control to set the power supplied into the chamber 19 equal to the set power P_{set} , it is possible to prevent an increase of
10 the load current CM caused by arc generation in the chamber 19.

Next, an eighth embodiment of the present invention will be described by referring to FIG. 9. An upper side circuit view of FIG. 9 is substantially
15 similar to that of FIG. 6. Thus, similar portions are denoted by similar reference numerals, and detailed description thereof will be omitted.

A load voltage VM , a load current CM , and a set current value I_{set} are input to a - terminal of the
20 operational amplifier 61. At this operational amplifier 61, $I_{set} \cdot L - CM \cdot L + VM \cdot T$ is calculated.

Then, at a divider 62, a process of dividing an output of the operational amplifier 61 by an input voltage V_i is carried out. A pulse width is decided by
25 an output of this divider 62. The output of the divider 62 is input through the switch S_2 to a sample holding circuit 63. An output of the sample holding

circuit 63 is input to a PWMIC 64. Drivers 56a, 56b are connected to the PWMIC 64. Conductance of the switching elements S11, S14 is controlled by the driver 56a, and conductance of the switching elements S13, S12 is controlled by the driver 56b.

A timing circuit 65 is connected to the PWMIC 64. The timing circuit 65 controls opening/closing of the switch S2 to sample-hold the output of the divider 62 which decides the pulse width of the PWM so that positive and negative pulses output to the switching elements S11 to S14 can be set equal to prevent magnetic saturation of the transformer T1.

According to the eighth embodiment of the present invention, since the pulse width is calculated by an average current of the cycle T as shown in the equation (6), in order to sufficiently reduce current ripples, inductance L is enlarged to enable shortening of the cycle T. That is, a PWM switching speed can be increased. Moreover, if the load voltage VM is reduced due to arc generation in the chamber 19, since a calculation result of the pulse width is obtained at a point of time when the load voltage VM is reduced, it is possible to limit an increase of the load current CM smaller.

Furthermore, the timing circuit 65 controls the opening/closing of the switch S2 to sample-hold the output of the divider 62 which decides the pulse width

of the PWM so that the positive and negative pulses
output to the switching elements S11 to S14 can be
set equal to prevent magnetic saturation of the
transformer T1. Thus, it is possible to prevent
5 magnetic saturation of the transformer T1.

Next, a ninth embodiment of the present invention
will be described by referring to FIG. 10. In FIG. 10,
portions similar to those of FIG. 1 or FIG. 9 are
denoted by similar reference numerals, and detailed
10 description will be omitted.

In FIG. 10, a set current value I_{set} input to
a - terminal of the operational amplifier 61 is set
based on an error between the instantaneous power and
the set power P_{set} of the sputtering power-supply unit.

15 That is, the ninth embodiment provides the
following effects in addition to those of the
aforementioned eighth embodiment. That is, the set
current I_{set} is decided so that power supplied to
the chamber 19 can be equal to the set power P_{set} .
20 Further, if arc is generated in the chamber 19, the
switch S1 is turned OFF to hold a value immediately
before the arc generation in the chamber 19 by the
error amplifier 22. Thus, during control to set the
power supplied into the chamber 19 equal to the set
25 power P_{set} , it is possible to prevent an increase of
the load current I_M caused by arc generation in the
chamber 19.

Next, a tenth embodiment of the present invention will be described by referring to FIG. 11. In FIG. 11, portions similar to those of FIG. 9 are denoted by similar reference numerals, and detailed description thereof will be omitted. In FIG. 11, a microcomputer 71 is installed. In this microcomputer 71, $I_{set} \cdot L - C M \cdot L + V M \cdot T$ is calculated, and divided by an input voltage V_i to calculate a pulse width. Other operations are processed by the same circuit as that of FIG. 9.

Thus, the tenth embodiment has the same effects as those of the aforementioned eighth embodiment, and can digitally process the calculation of the pulse width. Moreover, the digital processing of the pulse width calculation enables learning of a value of inductance L . Thus, by learning and controlling the value of the inductance L , it is possible to carry out higher-accuracy control.

Next, an eleventh embodiment of the present invention will be described by referring to FIG. 12. In FIG. 12, the function of the sample holding circuit 63 of FIG. 11 is carried out by a microcomputer 71. Thus, an output of a timing circuit 65 is input to the microcomputer 71 to control timing for executing software processing equivalent to the sample holding circuit 63.

Thus, the eleventh embodiment has the same effects

as those of the aforementioned eighth embodiment, and can digitally process calculation of a pulse width. Moreover, the digital processing of the pulse width calculation enables learning of a value of inductance L. Thus, by learning and controlling the value of the inductance L, it is possible to carry out higher-accuracy control.

Next, a twelfth embodiment of the present invention will be described by referring to FIG. 13. A circuit of FIG. 13 carries out processing of each of the PWMIC 64 and the timing circuit 65 of FIG. 12 by the microcomputer 71.

Thus, a PWM pulse is generated by the microcomputer 71, whereby a pulse width can be decided per pulse which causes no magnetic saturation by calculation of the microcomputer 71, while in the analog circuit of FIG. 9, the magnetic saturation of the transformer T1 is prevented by the pair of pulses. Moreover, the microcomputer 71 can accurately know magnetic history of the transformer T1.

Next, a thirteenth embodiment of the present invention will be described by referring to FIG. 14. In FIG. 14, a 3-phase AC voltage (AC 200 V3 ϕ) is subjected to all-wave rectification at a 3-phase rectification circuit D0, passed through a filter L0, pulse-output by a pair of switching circuits S10, S20, and then connected to primary sides of the transformers

T11, T12.

The switching circuit S10 has switching elements S11 to S14. The switching circuit S20 has switching elements S21 to S24. ON/OFF control of these switching
5 elements S11 to S14, S21 to S24 is carried out based on a control signal from a control section 121.

Additionally, a smoothing capacitor C11 is connected in parallel to the switching circuit S10, and a smoothing circuit C12 is connected in parallel to
10 the switching circuit S20.

A secondary side of the transformer T11 is connected to a bridge circuit B11 constituted of four diodes, and a secondary side of the transformer T12 is connected to a bridge circuit B12 constituted of four
15 diodes.

Further, another bridge circuit B13 is connected to the secondary side of the transformer T12.

One end of the bridge circuit B11 connected through four serially connected independent choke coils
20 L1 to L4, and further through a reverse-direction arc prevention circuit 113 to a (-) output terminal O1 of the unit. In this reverse-direction arc prevention circuit 113, a resistor R0 is connected in parallel to a diode D2.

25 Further, the other end of the bridge circuit B12 is connected to a (+) output terminal O2 of the unit. Additionally, a connection point between the choke coil

L4 and the reverse-direction arc prevention circuit 113 is connected through switching transistors SW21, 22 as switching means to an anode of a reverse voltage holding capacitor C31. These transistors SW21, SW22
5 are controlled by a driver 141. The driver 141 is controlled by a control signal from a control section 121.

In parallel with a serially connected body of the transistor SW21 and the transistor SW22, a serially
10 connected body 51 of protective barristers (constant voltage elements) D31, D32 is connected. A current detector 142 which detects a current I_b flowing through the protective barristers D31, D32 is connected to the serially connected body 151.

15 The bridge circuit B12 is serially connected to the bridge circuit B11. Further, the bridge circuit B13 is serially connected to the bridge circuit B12.

A connection point between the bridge circuits B12 and B13 is connected to a cathode of the capacitor C31,
20 and to the (+) output terminal O2 of the unit. Further, the other end of the bridge circuit B13 is connected to an anode of the capacitor C31.

A serially connected body of partial pressure resistors R1, R2 is connected between the (-) output
25 terminal O1 and the (+) output terminal O2 of the unit. A potential V1 at a connection point between these partial pressure resistors R1 and R2 is input to the

control section 121. A voltage detection section is constituted of the partial pressure resistors R1 and R2. The control section 121 is constituted of mainly, e.g., a microcomputer. The control section 121
5 detects the potential at the connection point between the partial pressure resistors R1 and R2 to detect a potential difference V between the (-) output terminal O1 and the (+) output terminal O2 of the unit.

The aforementioned switching elements S11 to S14,
10 S21 to S24 and the driver 141 are controlled by the control section 121.

A current I_a flowing through the four serially connected independent choke coils L1 to L4 is detected by a current detector 122. The current I_a detected by
15 this current detector 122 is output to the control section 121.

The (-) output terminal O1 of the unit is connected to a sputter source 131, and the (+) output terminal O2 is connected to a vacuum chamber 132.
20 Normally, the (+) output terminal O2 of the unit is grounded.

The control section 121 detects a potential difference V between the (-) output terminal O1 and the (+) output terminal O2 of the unit to determine
25 occurrence of sputtering discharge or arc discharge in the vacuum chamber 132. Since a sputtering voltage is normally 300 V or higher, and an arc discharge voltage

is 150 V or lower, when the potential difference V between the (-) output terminal O1 and the (+) output terminal O2 of the unit is reduced to 150 V or lower, the occurrence of arc discharge in the vacuum chamber
5 132 is determined.

Upon detection of the occurrence of arc discharge, the control section 121 turns ON the transistors SW21 and SW22 for set time T2 (0.3 to 10 μ s) after passage of set time T1 (0.01 to 100 μ s). That is, a reverse
10 voltage pulse is applied to the sputter source 131. During this period, the switching elements S11 to S14 are controlled to be ON/OFF by the control section 121 so that a constant current can flow through the four serially connected independent choke coils L1 to L4.
15 That is, since the current Ia flowing through the four serially connected independent choke coils L1 to L4 is detected by the current detector 122, the control section 121 controls the switching elements S11 to S14 to be ON/OFF so that the current Ia can become
20 a constant current. Arc determination time T3 immediately after the application of the aforementioned reverse voltage pulse is set to 10 μ s (0.01 to 10 μ s) or lower. Then, if arc is determined again after passage of the arc determination time T3, a process is
25 carried out to turn ON the transistors SW21 and SW22 for set time T2 (0.3 to 10 μ s) after the set time T1 (0.01 to 100 μ s). Thereafter, while arc is detected,

the reverse voltage pulse is continuously applied until no arc is detected. Here, the transistors SW21 and SW22 are turned ON after the set time T1 from the arc determination because the arc may be self-quenched
5 before the passage of the set time T1.

Next, an operation of the thirteen embodiment of the present invention constituted in the foregoing manner will be described. For example, a case where a cable connecting the (-) output terminal 01 to
10 the sputter source 131 is cut will be described. In this case, the current Ia flowing through the transformers T11 and T12 is suddenly stopped. Accordingly, a voltage of the (-) output terminal 01 is increased irrespective of ON/OFF states of the
15 transistors SW21 and 22. Then, when the voltage of the (-) output terminal 01 becomes a predetermined voltage or higher, a current flows through the protective barristers D31, D32 connected in parallel with the serially connected body of the switching transistors
20 SW21, SW22. This current Ib is detected by a current detector 142.

When it determines in determination time that the current Ib input from the current detector 142 exceeds a reference level, the control circuit 121 outputs OFF
25 signals to all the switching elements of the switching circuits S10 and S20.

Thus, when it is determined that the current

flowing through the barristers D31, D32, which is detected by the current detector 142, exceeds the reference level, the OFF signals are output to all the switching elements of the switching circuits S10 and S20 to prevent further flowing of the current. Thus, it is possible to prevent destruction of the barristers D31, D32.

Therefore, no voltage is supplied to the primary sides of the transformers T11 and T12. Then, the control circuit 121 carries out processing to wait until the current I_b detected by the current detector 142 becomes zero.

Upon detection that the current I_b detected by the current detector 142 becomes zero, the control circuit 121 resumes selective outputting of ON signals to the switching elements which constitute the switching circuits S10 and S20. As a result, a pulse voltage is input to the primary sides of the transformers T11 and T12, and a voltage (1200 to 1500 V) for discharge starting is generated in the (-) output terminal 01.

Incidentally, if total inductance of the L1 to L4 is 10 mH, and a sputtering current is 10 A, energy $EL1$ is represented as follows:

$$EL1 = 0.01 \times 10A \times 10A / 2 = 0.5 \text{ [J]}$$

If operating voltages of the barristers D31, D32 are 1600 to 1800 V, an average 1700 V,

$$1700 \text{ V} = L \cdot di/dt$$

$dt = 0.01H \cdot 10A / 1700 V = 5.88e^{-5}$ are set. Energy of 60 μs and inductance L1 to L4 is absorbed by the barristers D31, D32.

Even in a case where there is no more Ar gas for sputtering discharge, and discharging cannot be carried out, by the energy stored in the inductance L1 to L4, a current flows through the barristers D31, D32 similarly to the aforementioned operation. This current Ib is detected by the current detector 142.

When it determines in determination time that the current Ib input from the current detector 142 exceeds a reference level, the control circuit 121 outputs OFF signals to all the switching elements of the switching circuits S10 and S20. Accordingly, no voltage is supplied to the primary sides of the transformer T11 and T12. Then, the control circuit 121 carries out processing to wait until the current Ib detected by the current detector 142 becomes zero.

Upon detection that the current Ib detected by the current detector 142 becomes zero, the control circuit 121 resumes selective outputting of ON signals to the switching elements which constitute the switching circuits S10 and S20.

Thus, even if a cable connecting (-) output terminal 01 to the sputter source 131 is cut, a voltage applied to the transistors SW21 and SW22 is absorbed by the barristers D31, D32 and, by detecting a current

flowing through the barristers D31, D32, it is possible to prevent destruction of the barristers D31, D32.

Next, a fourteenth embodiment of the present invention will be described by referring to FIG. 15.

5 In FIG. 15, portions similar to those of FIG. 14 are denoted by similar reference numerals, and detailed description thereof will be omitted.

According to the fourteenth embodiment, in place of the serially connected body 151 where the barristers
10 D32, D32 and the current detector 142 are arranged, a constant voltage power source CV constituted of diodes D3, D4 may be disposed.

An operation of the fourteenth embodiment is similar to that of the thirteenth embodiment, and this
15 description will be omitted.

According to the present invention, it is possible to provide a sputtering power-supply unit which can reduce fluctuation in a sputtering current even if arc discharge occurs.